

PATENT 1794-0142P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicants:

Hideki HIRAYAMA et al.

Conf:

8855

Serial No.:

09/943,222

Art Unit:

1765

#10A

Filed:

August 31, 2001

Examiner:

M.J. SONG

mw

For:

LOW DISLOCATION BUFFER AND PROCESS FOR PRODUCTION

THEREOF AS WELL AS DEVICE PROVIDED WITH LOW

DISLOCATION BUFFER

RECEIVED

AMENDMENT UNDER 37 C.F.R. §1.111

APR 1 4 2003

TC 1700 April 8, 2003

Assistant Commissioner for Patents Washington, DC 20231

Sir:

In response to the Office Action mailed December 09, 2002 (Paper No. 8), the period of response having been extended one (1) month to April 9, 2003, the following amendments and remarks are respectfully submitted in connection with the above-identified application:

IN THE CLAIMS:

Please rewrite claims 1-9 and 19-26 as follows:

1. (Amended) A buffer formed between a substrate and a nitride semiconductor as a device material to be formed for constituting a device structure on said substrate, comprising:

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